SN74AHC595-Q1 具有三态输出寄存器的汽车类 8 位移位寄存器

1 特性

- 符合汽车应用要求
- 工作范围为 2V 至 5.5V V_{CC}
- 8 位串行输入、并行输出移位寄存器
- 移位寄存器具有直接清除功能

2 应用

- 启用或禁用数字信号
- 控制指示灯 LED
- 通信模块和系统控制器之间的转换

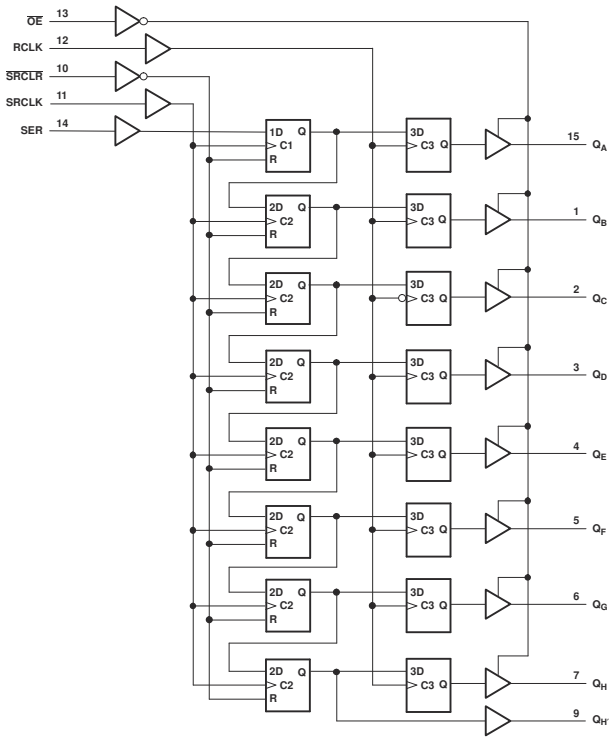
3 说明

SN74AHC595 包含一个可对 8 位 D 类存储寄存器进行馈送的 8 位串行输入、并行输出移位寄存器。

封装信息

器件型号	封装(1)	封装尺寸(2)	本体尺寸(3)
SN74AHC595-Q1	BQB（WQFN，16）	3.5mm x 2.5mm	3.5mm x 2.5mm
	PW（TSSOP，16）	5.00mm x 6.40mm	5.00mm x 4.4mm

(1) 如需了解更多信息，请参阅第 11 节。
(2) 封装尺寸（长 × 宽）为标称值，并包括引脚（如适用）。
(3) 本体尺寸（长 × 宽）为标称值，不包括引脚。



逻辑图（正逻辑）

Table of Contents

4 Pin Configuration and Functions

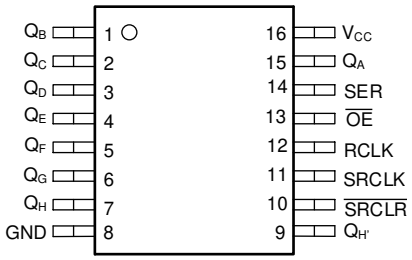


图 4-1. PW Package, 16-PIN TSSOP (Top View)

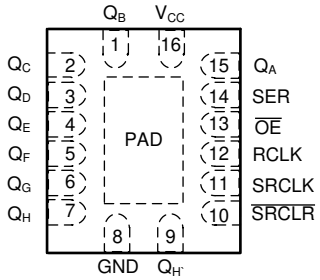


图 4-2. BQB Package, 16-Pin WQFN (Top View)

表 4-1. Pin Functions

PIN		TYPE(1)	DESCRIPTION
NAME	NO.		
Q_B	1	O	Q_B Output
Q_C	2	O	Q_C Output
Q_D	3	O	Q_D Output
Q_E	4	O	Q_E Output
Q_F	5	O	Q_F Output
Q_G	6	O	Q_G Output
Q_H	7	O	Q_H Output
GND	8	G	Ground Pin
$Q_{H'}$	9	O	$Q_{H'}$ Output
$\overline{SRCLR}$	10	I	$\overline{SRCLR}$ Input
SRCLK	11	I	SRCLK Input
RCLK	12	I	RCLK Input
$\overline{OE}$	13	I	Output Enable Pin. Active LOW
SER	14	I	SER Input
Q_A	15	O	Q_A Output
V_{CC}	16	P	Power Pin

(1) I = Input, O = Output, I/O = Input or Output, G = Ground, P = Power

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		–0.5	7	V
V_I	Input voltage range(2)		–0.5	7	V
V_O	Output voltage range(2)		–0.5	V_{CC} + 0.5	V
I_{IK}	Input clamp current	(V_I < 0)		–20 mA	mA
I_{OK}	Output clamp current	(V_O < 0 or V_O > V_{CC})		±20 mA	mA
I_O	Continuous output current	(V_O = 0 to V_{CC})		±25 mA	mA
	Continuous current through V_{CC} or GND			±75 mA	mA
T_{stg}	Storage temperature range		–65	150	°C

(1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

5.2 Recommended Operating Conditions

over recommended operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V_{CC}	Supply voltage		2	5.5	V
V_{IH}	High-level input voltage	V_{CC} = 2 V	1.5		V
		V_{CC} = 3 V	2.1		
		V_{CC} = 5.5 V	3.85		
V_{IL}	Low-level input voltage	V_{CC} = 2 V		0.5	V
		V_{CC} = 3 V		0.9	
		V_{CC} = 5.5 V		1.65	
V_I	Input voltage		0	5.5	V
V_O	Output voltage		0	V_{CC}	V
I_{OH}	High-level output current	V_{CC} = 2 V		–50	µA
		V_{CC} = 3.3 V ± 0.3 V		–4	mA
		V_{CC} = 5 V ± 0.5 V		–8	
I_{OL}	Low-level output current	V_{CC} = 2 V		50	µA
		V_{CC} = 3.3 V ± 0.3 V		4	mA
		V_{CC} = 5 V ± 0.5 V		8	
$\Delta t/\Delta v$	Input transition rise or fall rate	V_{CC} = 3.3 V ± 0.3 V		100	ns/V
		V_{CC} = 5 V ± 0.5 V		20	
T_A	Operating free-air temperature	I-suffix devices	–40	85	°C
		Q-suffix devices	–40	125	

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

5.3 Thermal Information

THERMAL METRIC(1)		BQB (WQFN)	PW (TSSOP)	UNIT
		16 PINS	16 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	91.8	135.9	°C/W

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report (SPRA953).

5.4 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V_{CC}	T_A = 25°C			MIN	MAX	UNIT
			MIN	TYP	MAX			
V_{OH}	I_{OH} = – 50 μA	2 V	1.9	2		1.9		V
		3 V	2.9	3		2.9		
		4.5 V	4.4	4.5		4.4		
	I_{OH} = – 4 mA	3 V	2.58			2.48		
	I_{OH} = – 8 mA	4.5 V	3.94			3.8		
V_{OL}	I_{OL} = 50 μA	2 V			0.1		0.1	V
		3 V			0.1		0.1	
		4.5 V			0.1		0.1	
	I_{OL} = 4 mA	3 V			0.36		0.44	
	I_{OL} = 8 mA	4.5 V			0.36		0.44	
I_I	V_I = 5.5 V or GND	0 V to 5.5 V			±0.1		±1	μA
I_{OZ}	Q_A – Q_H, V_I = V_{CC} or GND, V_O = V_{CC} or GND, $\overline{OE}$ = V_{IH} or V_{IL}	5.5 V			±0.25		±10	μA
I_{CC}	V_I = V_{CC} or GND, I_O = 0	5.5 V			4		40	μA
C_i	V_I = V_{CC} or GND	5 V		3	10		10	pF
C_o	V_O = V_{CC} or GND	5 V		5.5				pF

5.5 Timing Requirements, V_{CC} = 3.3 V ± 0.3 V

V_{CC} = 3.3 V ± 0.3 V, over recommended operating free-air temperature range (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

			T_A = 25°C		MIN	MAX	UNIT
			MIN	MAX			
t_w	Pulse duration	SRCLK high or low	5.5		6.5		ns
		RCLK high or low	5.5		6.5		
		$\overline{SRCLR}$ low	5		6		
t_{su}	Setup time	SER before SRCLK ↑	3.5		4.5		ns
		SRCLK ↑ before RCLK ↑ (1)	8		9.5		
		$\overline{SRCLR}$ low before RCLK ↑	8		10		
		$\overline{SRCLR}$ high (inactive) before SRCLK ↑	3		4		
t_h	Hold time	SER after SRCLK ↑	1.5		2.5		ns

(1) This setup time allows the storage register to receive stable data from the shift register. The clocks can be tied together, in which case the shift register is one clock pulse ahead of the storage register.

5.6 Timing Requirements, V_{CC} = 5 V ± 0.5 V

V_{CC} = 5 V ± 0.5 V, over recommended operating free-air temperature range (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

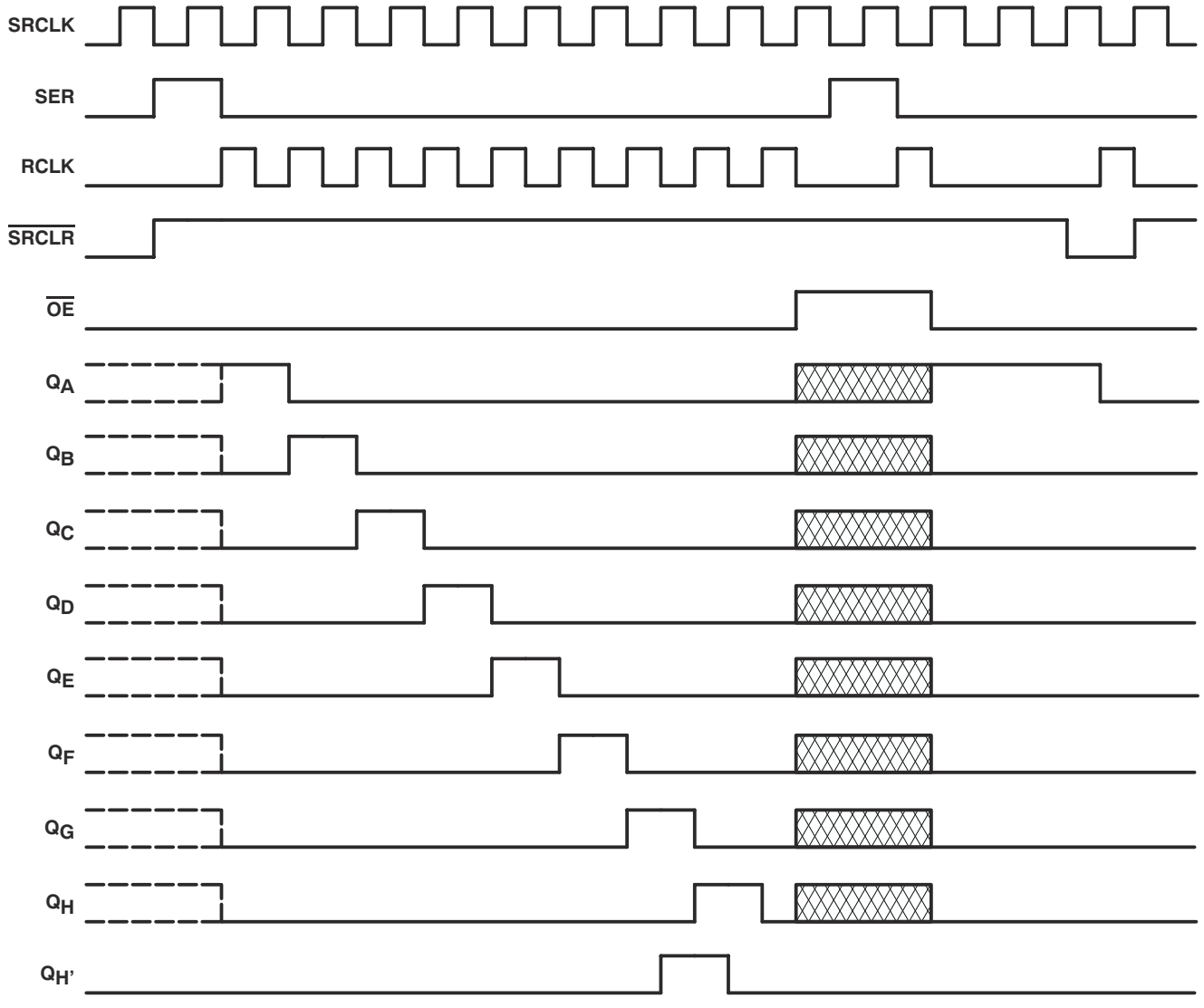
			T_A = 25°C		MIN	MAX	UNIT
			MIN	MAX			
t_w	Pulse duration	SRCLK high or low	5		6		ns
		RCLK high or low	5		6		
		$\overline{SRCLR}$ low	5.2		6.2		

V_{CC} = 5 V ± 0.5 V, over recommended operating free-air temperature range (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

			T_A = 25°C		MIN	MAX	UNIT
			MIN	MAX			
t_{su}	Setup time	SER before SRCLK ↑	3		4		ns
		SRCLK ↑ before RCLK ↑ (1)	5		6		
		$\overline{SRCLR}$ low before RCLK ↑	5		6		
		$\overline{SRCLR}$ high (inactive) before SRCLK ↑	2.5		3.5		
t_h	Hold time	SER after SRCLK ↑	2		3		ns

(1) This setup time allows the storage register to receive stable data from the shift register. The clocks can be tied together, in which case the shift register is one clock pulse ahead of the storage register.

5.7 Timing Diagrams



NOTE: ▨ implies that the output is in 3-State mode.

5.8 Switching Characteristics, V_{CC} = 3.3 V ± 0.3 V

V_{CC} = 3.3 V ± 0.3 V, over recommended operating free-air temperature range (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

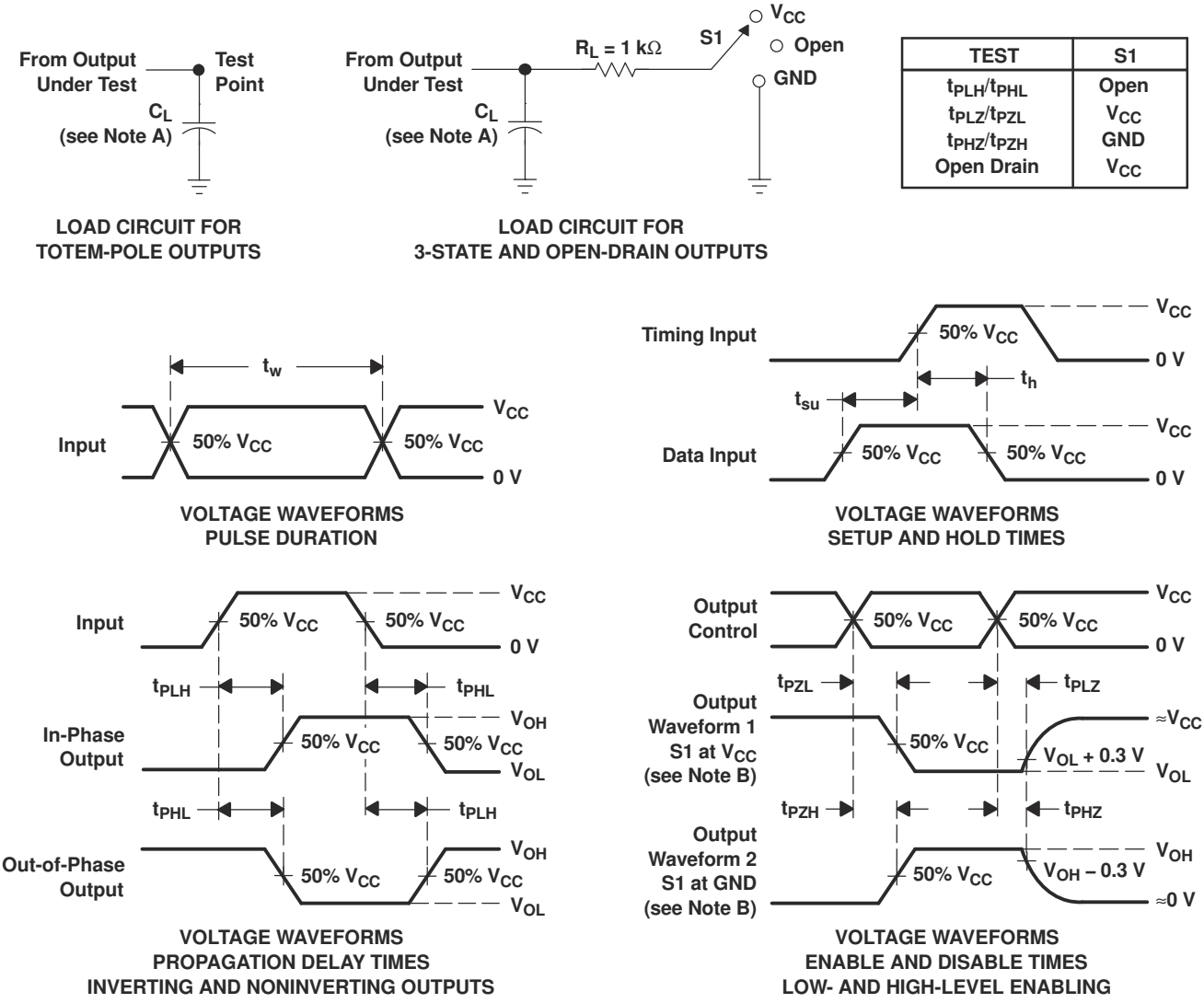
PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T_A = 25°C			MIN	MAX	UNIT
				MIN	TYP	MAX			
f_{max}			C_L = 50 pF	55	105		40		MHz
t_{PLH}	RCLK	Q_A – Q_H	C_L = 50 pF		7.9	15.4	1	20	ns
t_{PHL}					7.9	15.4	1	20	
t_{PLH}	SRCLK	$Q_{H'}$	C_L = 50 pF		9.2	16.5	1	21.5	ns
t_{PHL}					9.2	16.5	1	21.5	
t_{PHL}	$\overline{SRCLR}$	$Q_{H'}$	C_L = 50 pF		9	16.3	1	20.2	ns
t_{PZH}	$\overline{OE}$	Q_A – Q_H	C_L = 50 pF		7.8	15	1	20	ns
t_{PZL}					9.6	15	1	20	
t_{PHZ}	$\overline{OE}$	Q_A – Q_H	C_L = 50 pF		8.1	15.7	1	19.2	ns
t_{PLZ}					9.3	15.7	1	19.2	

5.9 Switching Characteristics, V_{CC} = 5 V ± 0.5 V

V_{CC} = 5 V ± 0.5 V, over recommended operating free-air temperature range (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T_A = 25°C			MIN	MAX	UNIT
				MIN	TYP	MAX			
f_{max}			C_L = 50 pF	95	140		75		MHz
t_{PLH}	RCLK	Q_A – Q_H	C_L = 50 pF		5.6	9.4	1	13.5	ns
t_{PHL}					5.6	9.4	1	13.5	
t_{PLH}	SRCLK	$Q_{H'}$	C_L = 50 pF		6.4	10.2	1	14.4	ns
t_{PHL}					6.4	10.2	1	14.4	
t_{PHL}	$\overline{SRCLR}$	$Q_{H'}$	C_L = 50 pF		6.4	10	1	14.1	ns
t_{PZH}	$\overline{OE}$	Q_A – Q_H	C_L = 50 pF		5.7	10.6	1	15	ns
t_{PZL}					6.8	10.6	1	15	
t_{PHZ}	$\overline{OE}$	Q_A – Q_H	C_L = 50 pF		3.5	10.3	1	14	ns
t_{PLZ}					3.4	10.3	1	14	

6 Parameter Measurement Information



NOTES: A. C_L includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 1 MHz, Z_O = 50 Ω, t_r ≤ 3 ns, t_f ≤ 3 ns.
D. The outputs are measured one at a time, with one input transition per measurement.

图 6-1. Load Circuit and Voltage Waveforms

7 Detailed Description

7.1 Overview

The SN74AHC595 contains an 8-bit serial-in, parallel-out shift register that feeds an 8-bit D-type storage register. The storage register has parallel 3-state outputs. Separate clocks are provided for both the shift and storage registers.

The shift register has a direct overriding clear ($\overline{SRCLR}$) input, serial (SER) input, and a serial output for cascading. When the output-enable ($\overline{OE}$) input is high, all outputs, except $Q_{H'}$, are in the high-impedance state.

Both the shift-register clock (SRCLK) and storage-register clock (RCLK) are positive-edge triggered. If both clocks are connected together, the shift register always is one clock pulse ahead of the storage register.

7.2 Functional Block Diagram

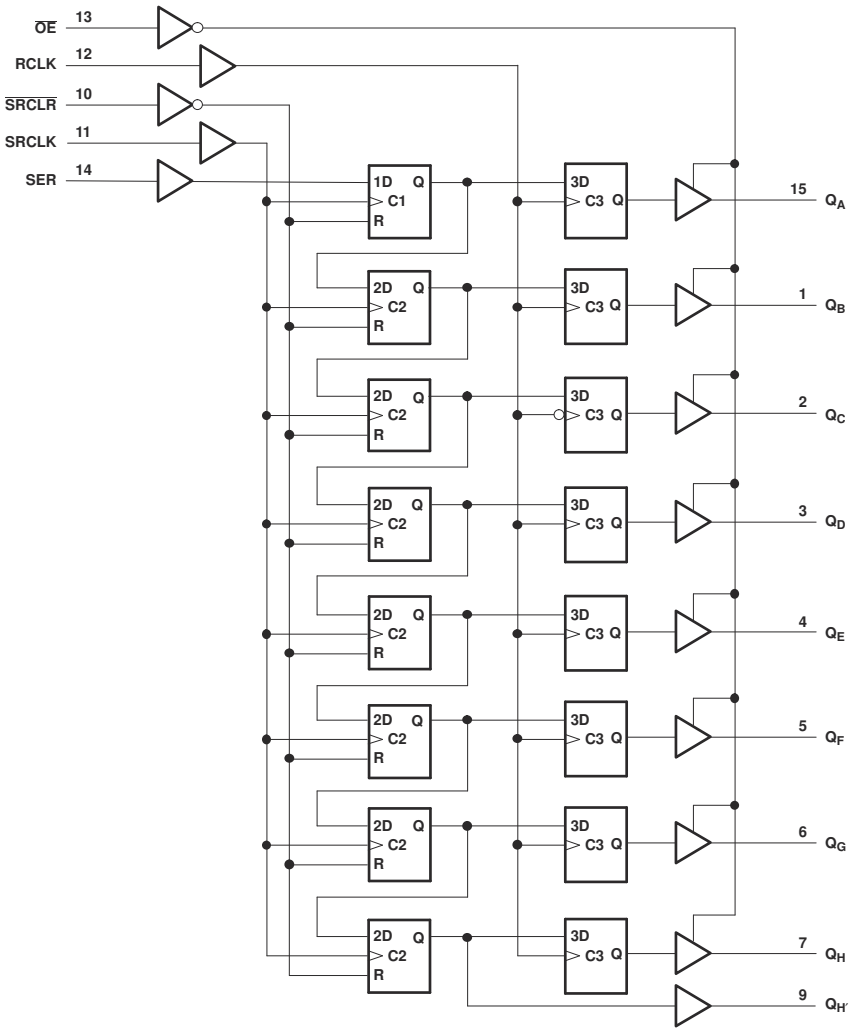


图 7-1. Logic Diagram (Positive Logic)

7.3 Device Functional Modes

表 7-1. Function Table

INPUTS					FUNCTION
SER	SRCLK	$\overline{\text{SRCLR}}$	RCLK	$\overline{\text{OE}}$	
X	X	X	X	H	Outputs Q_A – Q_H are disabled.
X	X	X	X	L	Outputs Q_A – Q_H are enabled.
X	X	L	X	X	Shift register is cleared.
L	↑	H	X	X	First stage of the shift register goes low. Other stages store the data of previous stage, respectively.
H	↑	H	X	X	First stage of the shift register goes high. Other stages store the data of previous stage, respectively.
X	X	X	↑	X	Shift-register data is stored into the storage register.

8 Application and Implementation

备注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI’s customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. A 0.1-μF capacitor is recommended for this device. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. The 0.1-μF and 1-μF capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results, as shown in the following layout example.

8.2 Layout

8.2.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices, inputs must never be left floating. In many cases, functions or parts of functions of digital logic devices are unused (for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used). Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or V_{CC}, whichever makes more sense for the logic function or is more convenient.

8.2.2 Layout Example

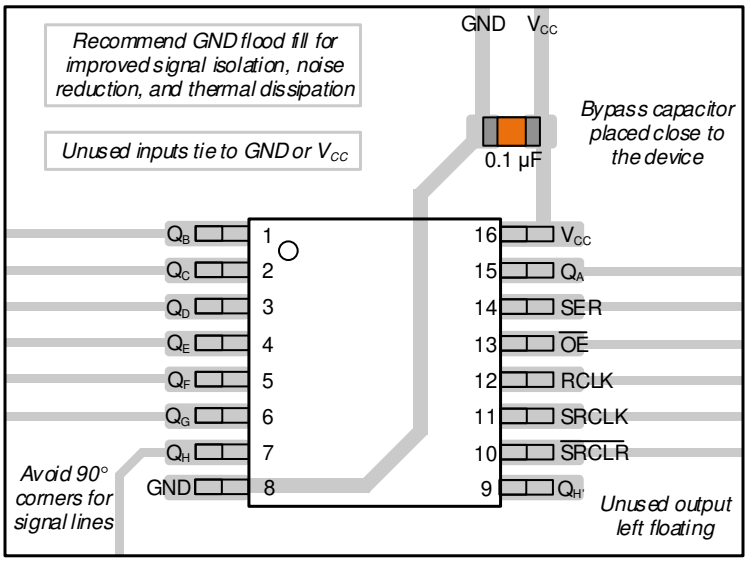


图 8-1. Example Layout for the SN74AHC595-Q1

9 Device and Documentation Support

9.1 Document Support (Analog)

9.1.1 Related Documentation

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

表 9-1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
SN74AHC595-Q1	Click here	Click here	Click here	Click here	Click here

9.2 接收文档更新通知

要接收文档更新通知，请导航至 ti.com 上的器件产品文件夹。点击*通知* 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

9.3 支持资源

TI E2E™ 中文支持论坛是工程师的重要参考资料，可直接从专家处获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题，获得所需的快速设计帮助。

链接的内容由各个贡献者“按原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的使用条款。

9.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.
所有商标均为其各自所有者的财产。

9.5 静电放电警告

静电放电 (ESD) 会损坏这个集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

9.6 术语表

TI 术语表　　本术语表列出并解释了术语、首字母缩略词和定义。

10 Revision History

注：以前版本的页码可能与当前版本的页码不同

Changes from Revision D (March 2024) to Revision E (April 2024)	Page
• Updated thermal values for PW package from R θ JA = 108 to 135.9, all values in °C/W	5

Changes from Revision C (November 2023) to Revision D (March 2024)	Page
• 向*封装信息* 表、*引脚配置和功能* 部分和*热性能信息* 表中添加了 BQB 封装	1

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74AHC595QPWRQ1	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA595Q	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

OTHER QUALIFIED VERSIONS OF SN74AHC595-Q1 :

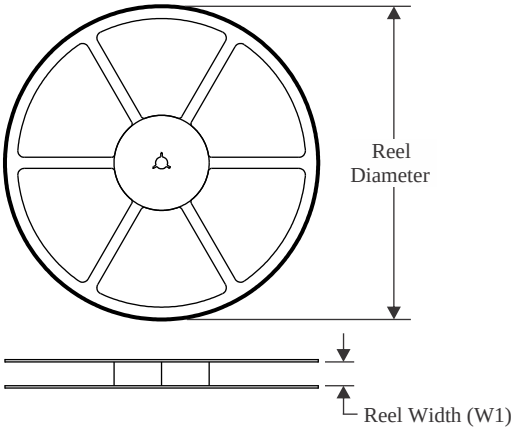
- Catalog : SN74AHC595

NOTE: Qualified Version Definitions:

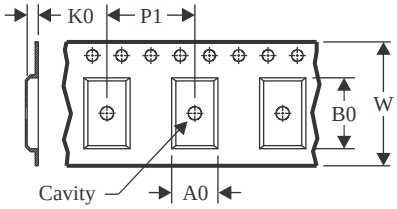
- Catalog - TI's standard catalog product

TAPE AND REEL INFORMATION

REEL DIMENSIONS

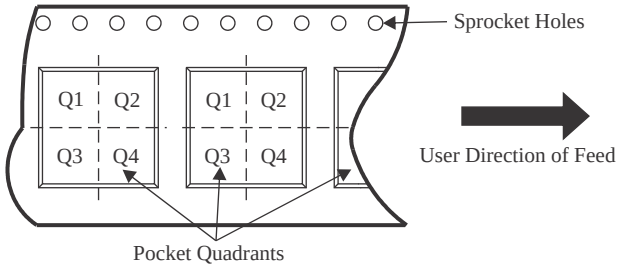


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

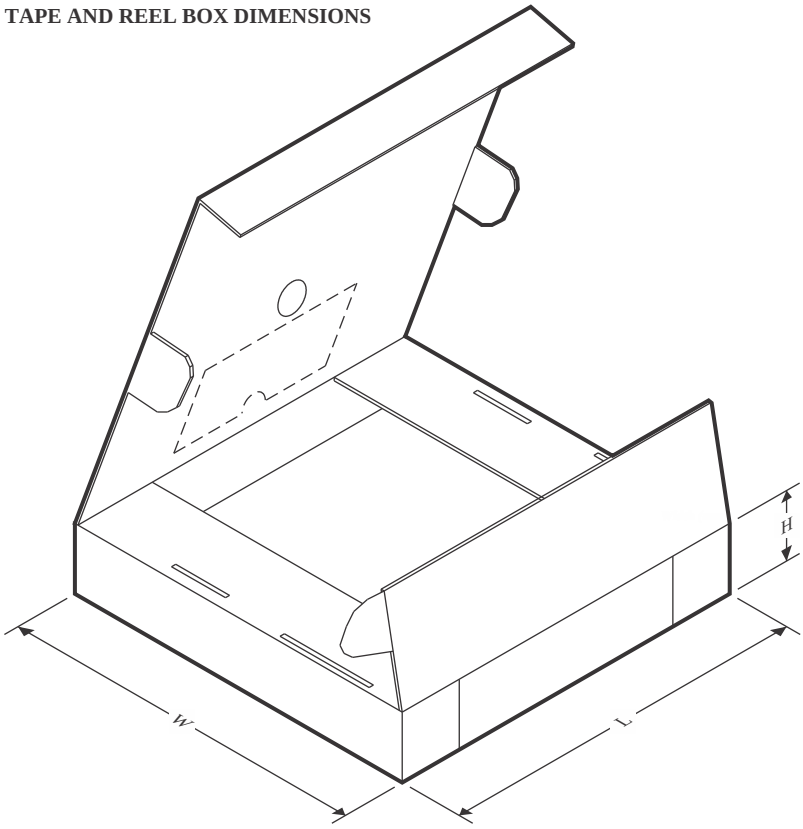
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHC595QPWRQ1	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

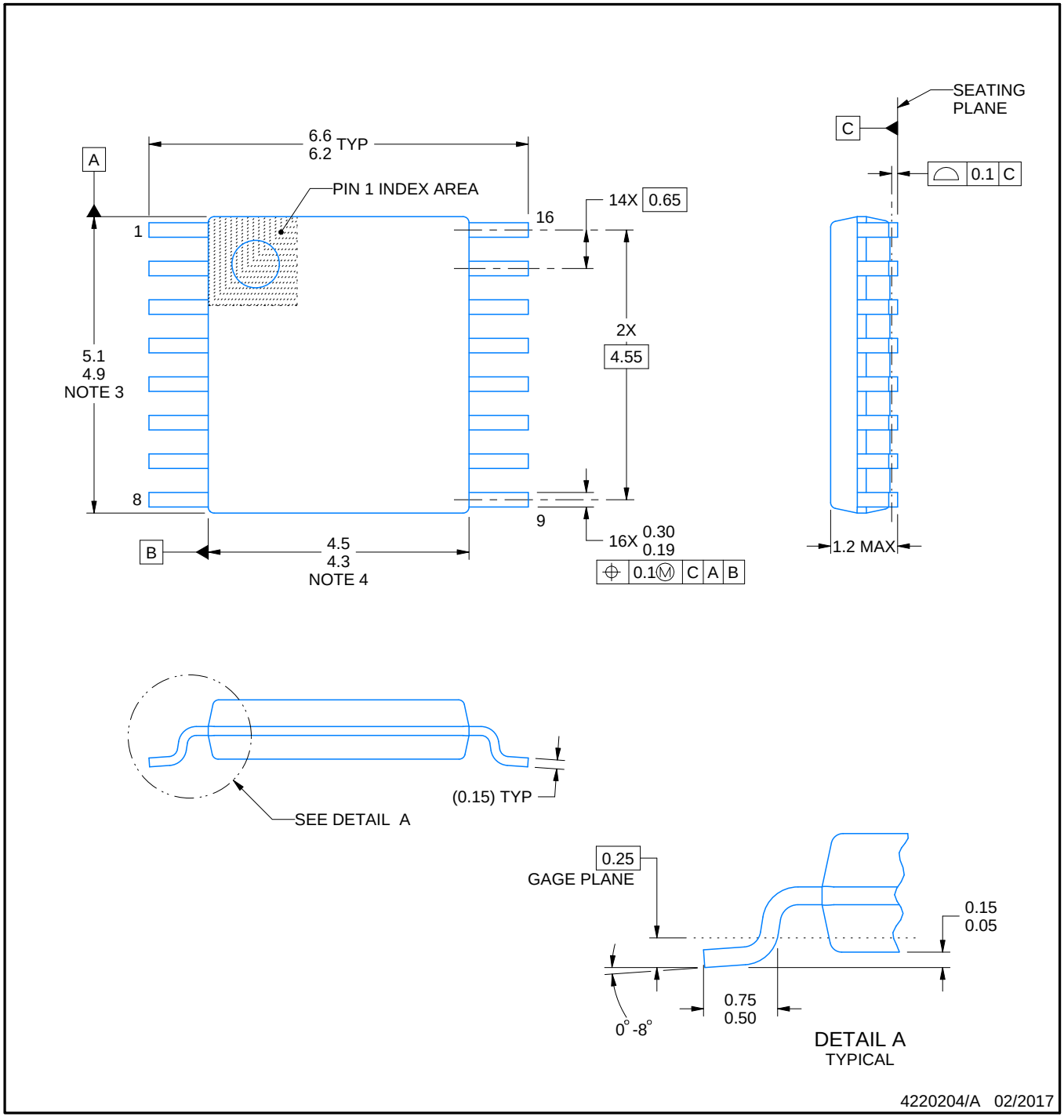
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AHC595QPWRQ1	TSSOP	PW	16	2000	356.0	356.0	35.0

PACKAGE OUTLINE

PW0016A

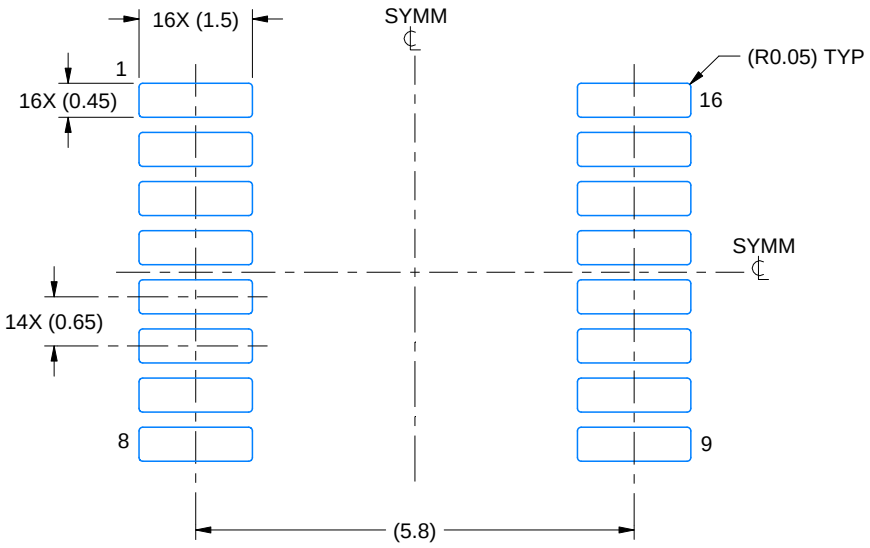
TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE

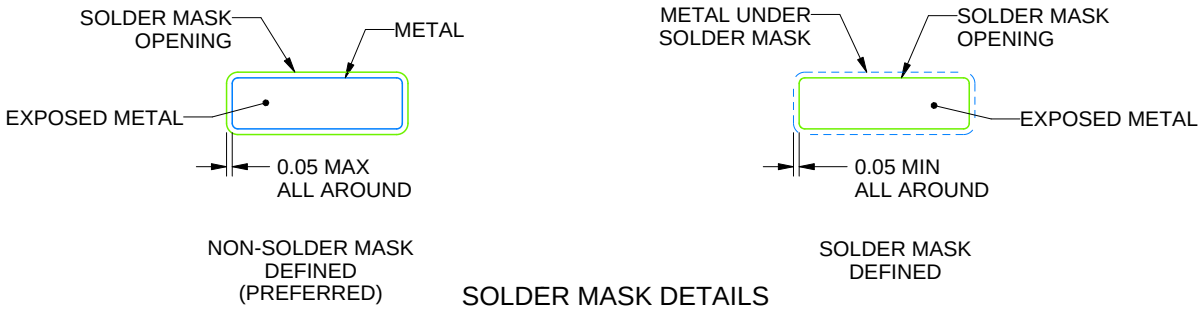


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



SOLDER MASK DETAILS

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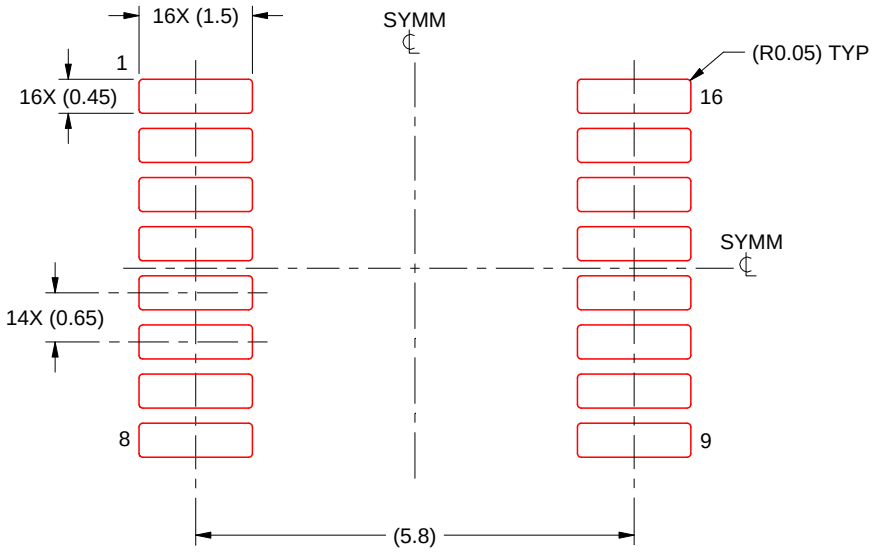
NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220204/A 02/2017

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

重要声明和免责声明

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